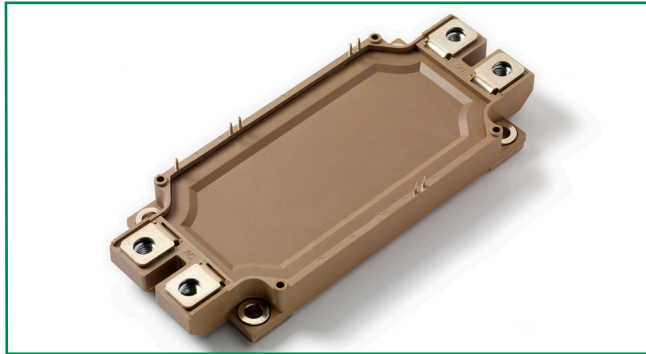


MG12300WB-BN2MM

Features

- IGBT³ CHIP(Trench+Field Stop technology)
- Low saturation voltage and positive temperature coefficient
- Fast switching and short tail current
- Free wheeling diodes with fast and soft reverse recovery
- Temperature sense included

Applications

- AC motor control
- Motion/servo control
- Photovoltaic/Fuel cell
- Inverter and power supplies

Module Characteristics ($T_J = 25^\circ\text{C}$, unless otherwise specified)

Symbol	Parameters	Test Conditions	Min	Typ	Max	Unit
$T_{J\max}$	Max. Junction Temperature				150	$^\circ\text{C}$
$T_{J\text{op}}$	Operating Temperature		-40		125	$^\circ\text{C}$
T_{stg}	Storage Temperature		-40		125	$^\circ\text{C}$
V_{isol}	Insulation Test Voltage	AC, t=1min		3000		V
CTI	Comparative Tracking Index		210			
Torque	Module-to-Sink	Recommended (M5)	2.5		5	N·m
Torque	Module Electrodes	Recommended (M6)	3		5	N·m
Weight				350		g

Absolute Maximum Ratings ($T_J = 25^\circ\text{C}$, unless otherwise specified)

Symbol	Parameters	Test Conditions	Values	Unit
IGBT				
V_{CES}	Collector - Emitter Voltage	$T_J=25^\circ\text{C}$	1200	V
V_{GES}	Gate - Emitter Voltage		± 20	V
I_{C}	DC Collector Current	$T_{\text{C}}=25^\circ\text{C}$	500	A
		$T_{\text{C}}=80^\circ\text{C}$	300	A
I_{CM}	Repetitive Peak Collector Current	$t_p=1\text{ms}$	600	A
P_{tot}	Power Dissipation Per IGBT		1400	W
Diode				
V_{RRM}	Repetitive Reverse Voltage	$T_J=25^\circ\text{C}$	1200	V
$I_{\text{F(AV)}}$	Average Forward Current	$T_{\text{C}}=25^\circ\text{C}$	300	A
		$T_{\text{C}}=80^\circ\text{C}$	180	A
I_{FRM}	Repetitive Peak Forward Current	$t_p=1\text{ms}$	600	A
I^2t		$T_J=125^\circ\text{C}$, t=10ms, $V_{\text{R}}=0\text{V}$	17500	A^2s

Electrical and Thermal Specifications ($T_J = 25^\circ\text{C}$, unless otherwise specified)

Symbol	Parameters	Test Conditions	Min	Typ	Max	Unit
IGBT						
$V_{GE(th)}$	Gate - Emitter Threshold Voltage	$V_{CE}=V_{GE}, I_C=12\text{mA}$	5.0	5.8	6.5	V
$V_{CE(sat)}$	Collector - Emitter	$I_C=300\text{A}, V_{GE}=15\text{V}, T_J=25^\circ\text{C}$		1.7		V
	Saturation Voltage	$I_C=300\text{A}, V_{GE}=15\text{V}, T_J=125^\circ\text{C}$		2.0		V
I_{ICES}	Collector Leakage Current	$V_{CE}=1200\text{V}, V_{GE}=0\text{V}, T_J=25^\circ\text{C}$			1	mA
		$V_{CE}=1200\text{V}, V_{GE}=0\text{V}, T_J=125^\circ\text{C}$			5	mA
I_{GES}	Gate Leakage Current	$V_{CE}=0\text{V}, V_{GE}=\pm 15\text{V}, T_J=125^\circ\text{C}$	-400		400	nA
R_{Gint}	Integrated Gate Resistor			2.5		Ω
Q_{ge}	Gate Charge	$V_{CE}=600\text{V}, I_C=300\text{A}, V_{GE}=\pm 15\text{V}$		2.7		μC
C_{ies}	Input Capacitance	$V_{CE}=25\text{V}, V_{GE}=0\text{V}, f=1\text{MHz}$		21		nF
C_{res}	Reverse Transfer Capacitance				1.0	
$t_{d(on)}$	Turn - on Delay Time	$V_{CC}=600\text{V}$ $I_C=300\text{A}$ $R_G=2.4\Omega$ $V_{GE}=\pm 15\text{V}$ Inductive Load	$T_J=25^\circ\text{C}$		160	ns
			$T_J=125^\circ\text{C}$		170	ns
t_r	Rise Time		$T_J=25^\circ\text{C}$		45	ns
			$T_J=125^\circ\text{C}$		50	ns
$t_{d(off)}$	Turn - off Delay Time		$T_J=25^\circ\text{C}$		460	ns
			$T_J=125^\circ\text{C}$		530	ns
t_f	Fall Time		$T_J=25^\circ\text{C}$		100	ns
			$T_J=125^\circ\text{C}$		150	ns
E_{on}	Turn - on Energy		$T_J=25^\circ\text{C}$		13	mJ
			$T_J=125^\circ\text{C}$		20	mJ
E_{off}	Turn - off Energy	$T_J=25^\circ\text{C}$		25	mJ	
		$T_J=125^\circ\text{C}$		37	mJ	
I_{SC}	Short Circuit Current	$t_{psc} \leq 10\mu\text{s}, V_{GE}=15\text{V}, T_J=125^\circ\text{C}, V_{CC}=900\text{V}$		1200		A
R_{thJC}	Junction-to-Case Thermal Resistance (Per IGBT)				0.09	K/W
Diode						
V_F	Forward Voltage	$I_F=300\text{A}, V_{GE}=0\text{V}, T_J=25^\circ\text{C}$		1.65		V
		$I_F=300\text{A}, V_{GE}=0\text{V}, T_J=125^\circ\text{C}$		1.6		V
t_{RR}	Reverse Recovery Time	$I_F=300\text{A}, V_R=600\text{V}$ $di_F/dt=-4800\text{A}/\mu\text{s}$ $T_J=125^\circ\text{C}$		225		ns
I_{RRM}	Max. Reverse Recovery Current			255		A
E_{rec}	Reverse Recovery Energy			24		mJ
R_{thJCD}	Junction-to-Case Thermal Resistance (Per Diode)				0.16	K/W

NTC Characteristics ($T_J = 25^\circ\text{C}$, unless otherwise specified)

Symbol	Parameters	Test Conditions	Min	Typ	Max	Unit
R_{25}	Resistance	$T_c=25^\circ\text{C}$		5		K Ω
$B_{25/50}$				3375		K

Figure 1: Typical Output Characteristics for IGBT Inverter

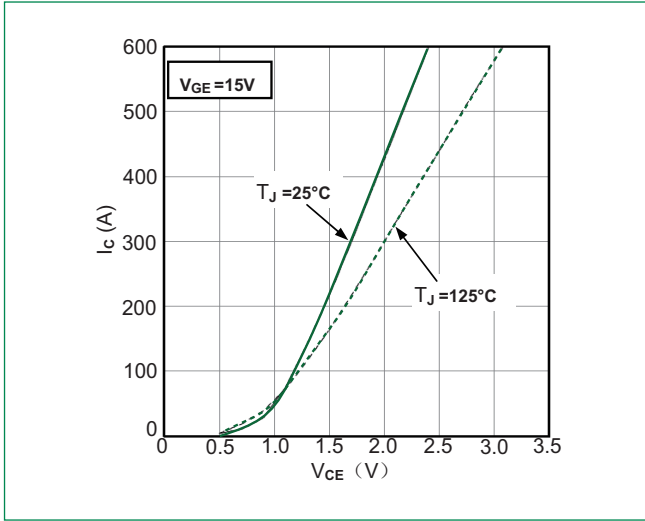


Figure 2: Typical Output Characteristics for IGBT Inverter

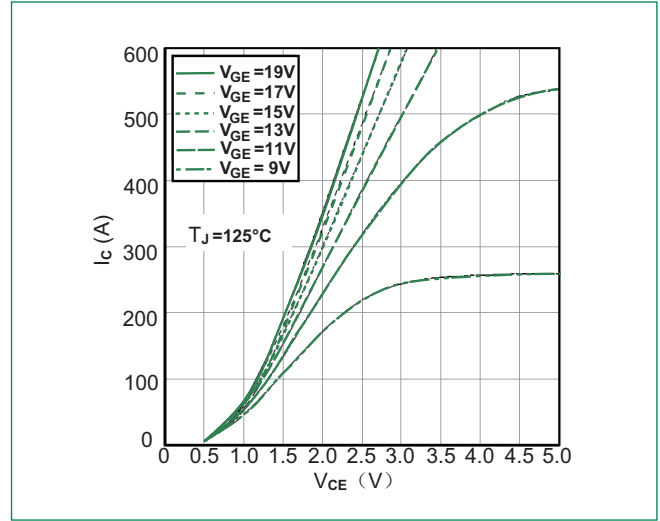


Figure 3: Typical Transfer Characteristics for IGBT Inverter

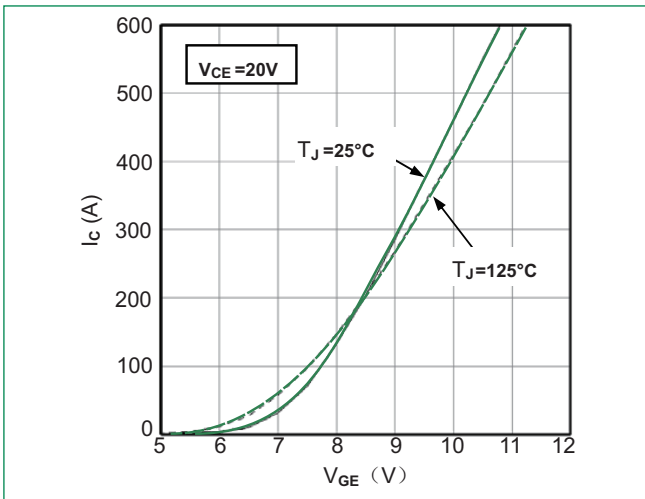


Figure 4: Switching Energy vs. Gate Resistor for IGBT Inverter

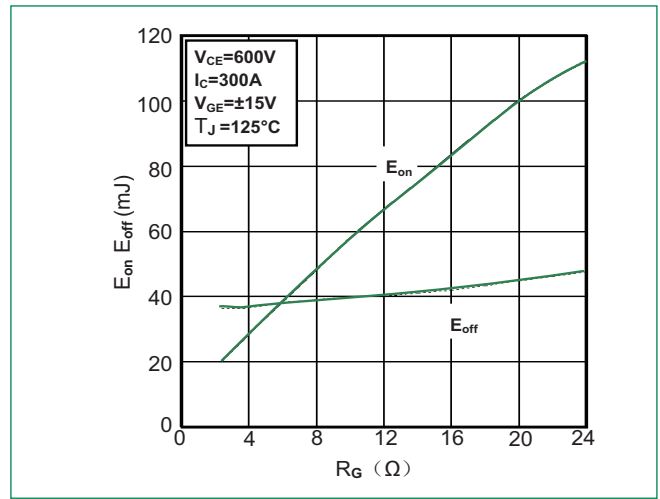


Figure 5: Switching Energy vs. Collector Current for IGBT Inverter

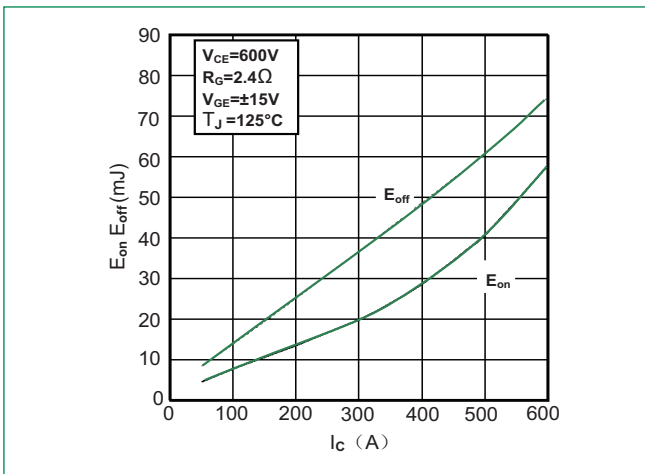


Figure 6: Reverse Biased Safe Operating Area for IGBT Inverter

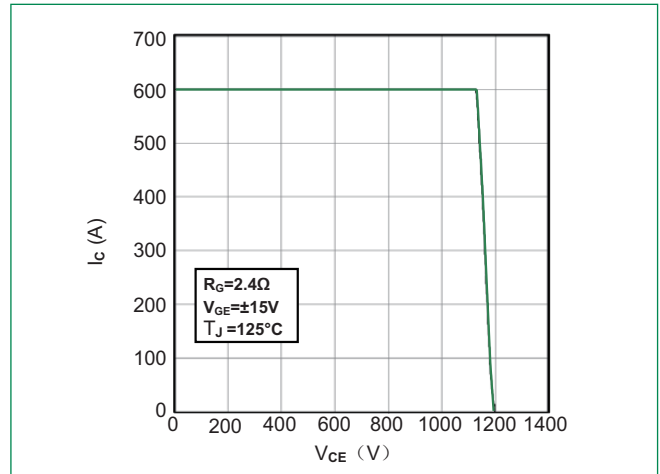


Figure 7: Diode Forward Characteristics for Diode Inverter

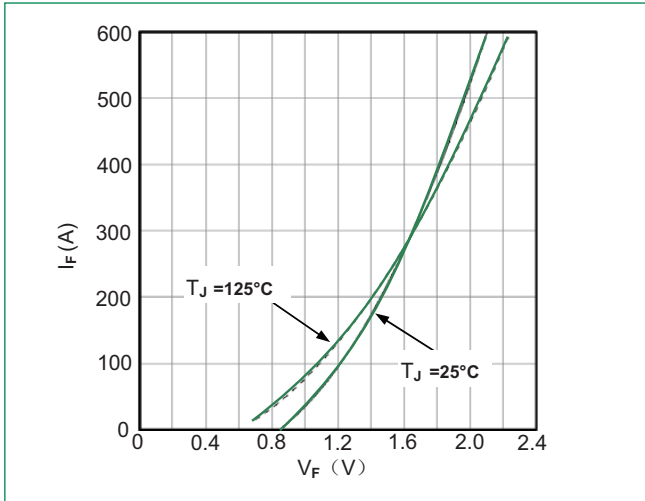


Figure 8: Switching Energy vs. Gate Resistort for Diode Inverter

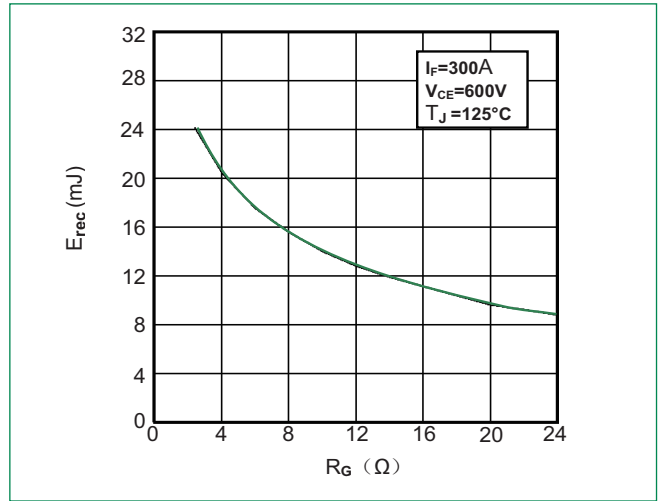


Figure 9: Transient Thermal Impedance of Diode and IGBT Inverter

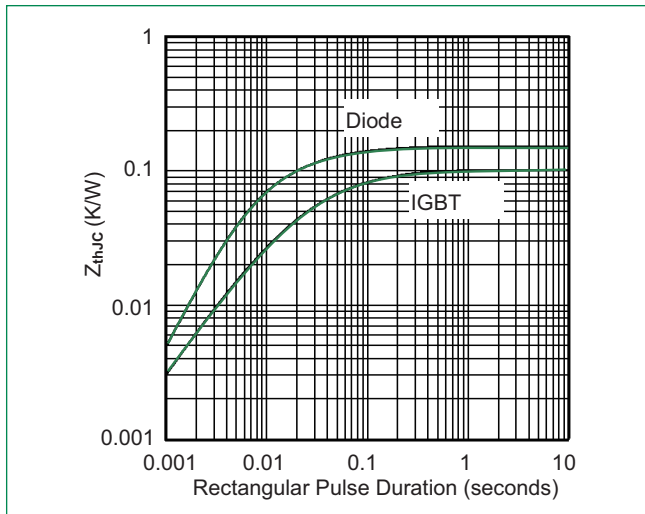
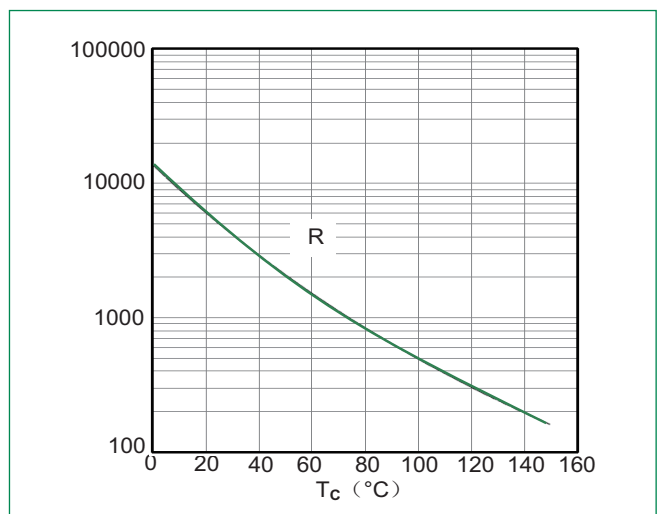


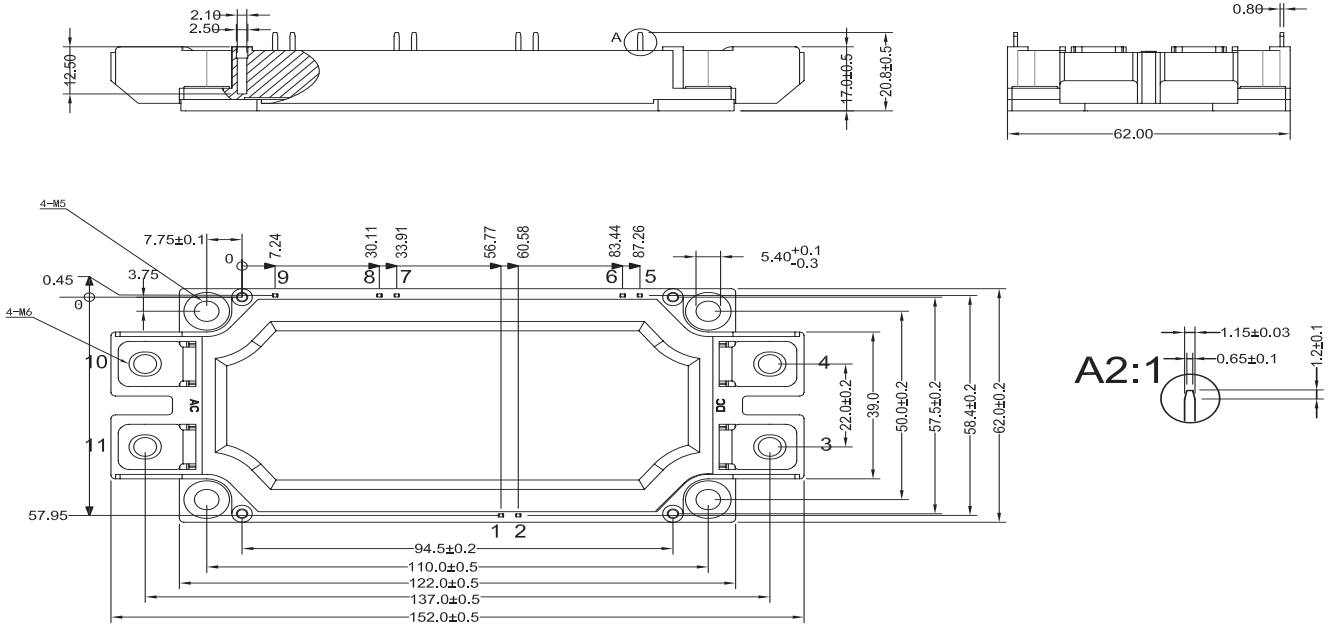
Figure 10: NTC Characteristics



Circuit Diagram



Dimensions-Package WB

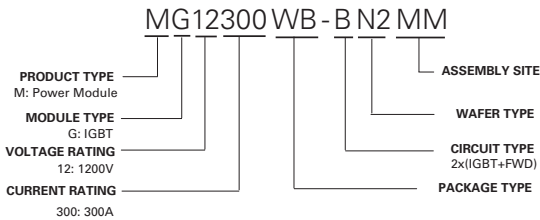


The foot pins are in gold / nickel coating

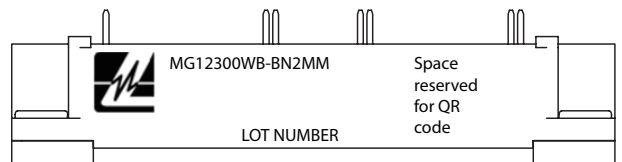
Packing Options

Part Number	Marking	Weight	Packing Mode	M.O.Q
MG12300WB-BN2MM	MG12300WB-BN2MM	350g	Bulk Pack	60

Part Numbering System



Part Marking System



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[FD401R17KF6C_B2](#) [FD-DF80R12W1H3_B52](#) [FF200R06YE3](#) [FF300R12KE4_E](#) [FF450R12ME4P](#) [FF600R12IP4V](#) [FP10R06W1E3_B11](#)
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[F475R07W1H3B11ABOMA1](#) [FD1400R12IP4D](#) [FD200R12PT4_B6](#) [FD800R33KF2C-K](#) [FF1200R17KP4_B2](#) [FF300R17KE3_S4](#)
[FF300R17ME4_B11](#) [FF401R17KF6C_B2](#) [FF650R17IE4D_B2](#) [FF900R12IP4D](#) [FF900R12IP4DV](#) [STGIF7CH60TS-L](#) [FP50R07N2E4_B11](#)
[FS100R07PE4](#) [FS150R07N3E4_B11](#) [FS150R17N3E4](#) [FS150R17PE4](#)